

# RDS60-24

## EVALUATION DATA

### 型式データ

DWG No. B028-53-01		
APPD	CHK	DWG
Kurosawa 9, Mar, '10	Ryuman 9, Mar, '10	Shimamura 9, Mar, '10

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Vin	..... 入力電圧 Input voltage
Vout	..... 出力電圧 Output voltage
Iin	..... 入力電流 Input current
Iout	..... 出力電流 Output current
Ta	..... 周囲温度 Ambient temperature
f	..... 周波数 Frequency
CNT (RC)	..... ON/OFFコントロール ON/OFF control

## 1. 測定方法

## Evaluation Method

## 1.1 測定回路

Circuit used for determination

測定回路1 Circuit 1

- ・静特性
- ・過電流保護特性
- ・過電圧保護特性
- ・出力立ち上がり・立ち下がり特性
- ・出力保持時間特性

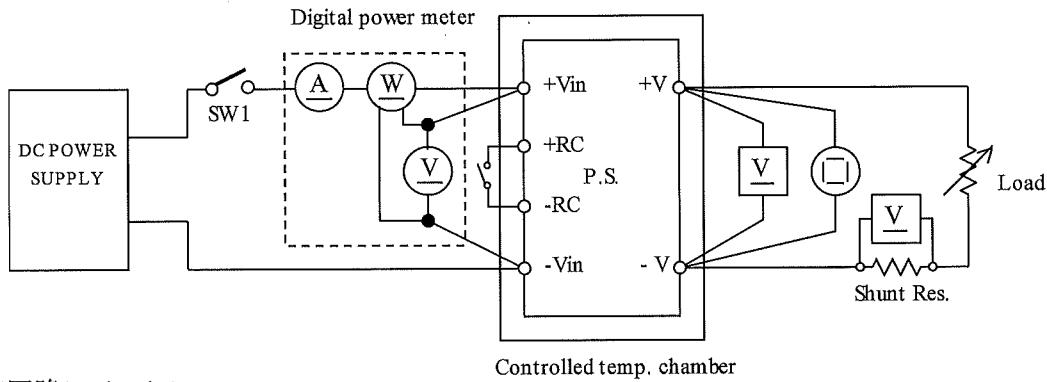
Steady state data

Over current protection (OCP) characteristics

Over voltage protection (OVP) characteristics

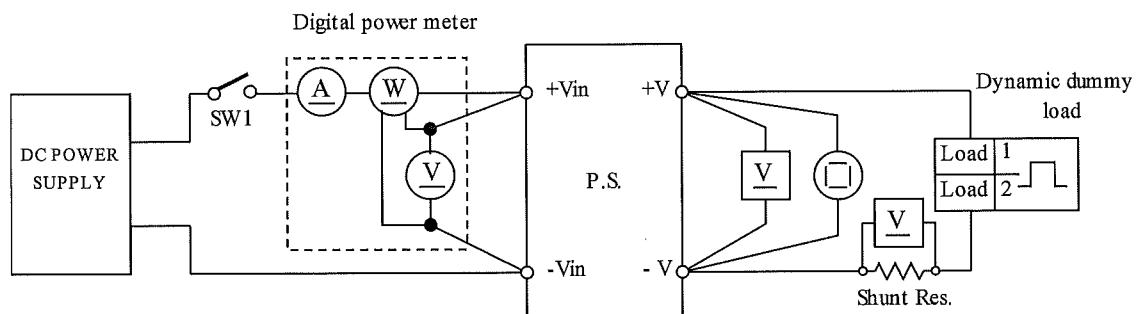
Output rise/fall characteristics

Hold up time characteristics

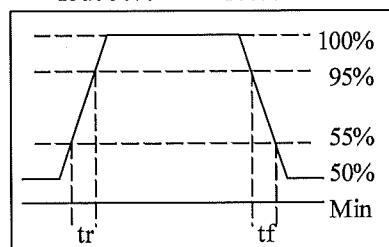
測定回路2 Circuit 2

- ・過渡応答（負荷急変）特性

Dynamic load response characteristics

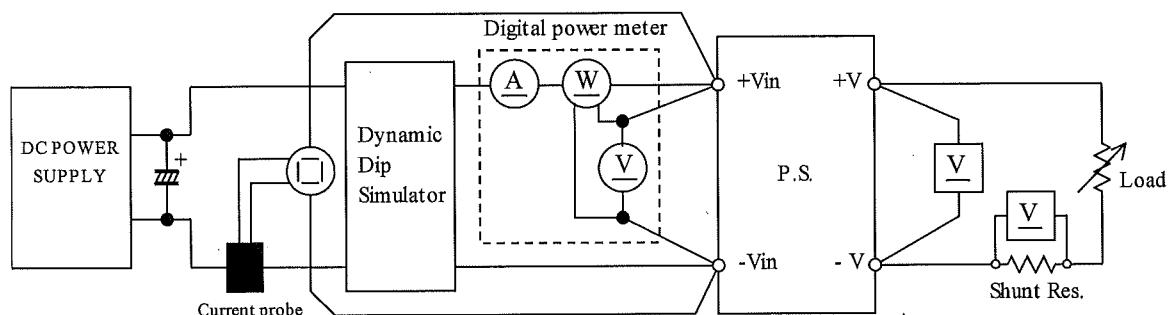


## Output current waveform

Iout 50%  $\leftrightarrow$  100%測定回路3 Circuit 3

- ・入力サージ電流（突入電流）特性

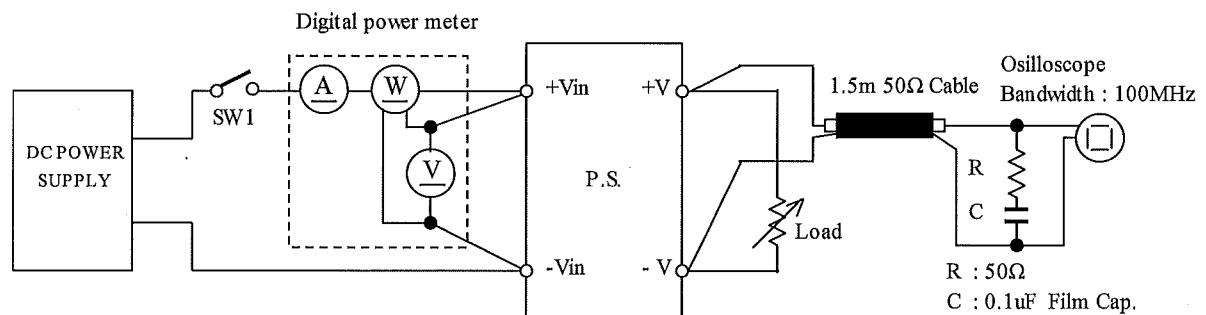
Inrush current characteristics



測定回路4 Circuit 4

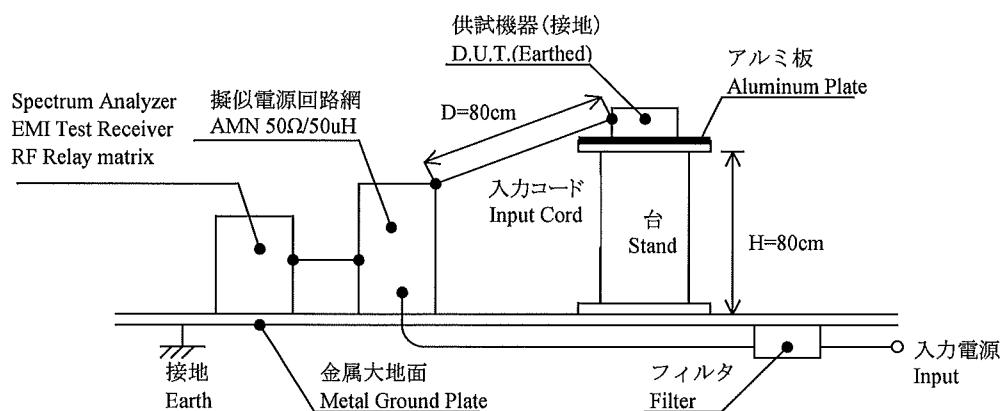
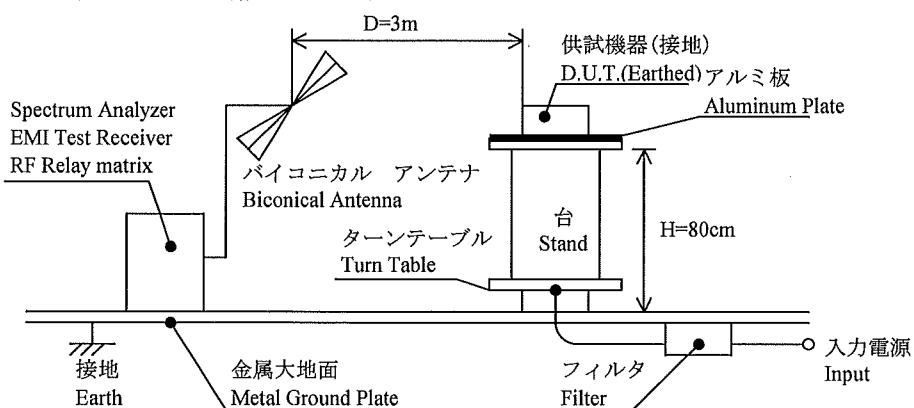
- 出力リップル、ノイズ特性  
Normal Mode (JEITA Standard RC-9131A)

Output ripple and noise waveform

測定構成 Configuration

- E M I 特性  
雑音端子電圧 (帰還ノイズ)

Electro-Magnetic Interference characteristics  
Conducted Emission Noise

雑音電界強度 (輻射ノイズ)

## 1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	TEKTRONIX	TDS3012
2	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL1740EL
3	DIGITAL MULTIMETER	AGILENT	34970A
4	DIGITAL POWER METER	YOKOGAWA ELECT.	WT110
5	CURRENT PROBE/AMPLIFIER	YOKOGAWA ELECT.	701930
6	DYNAMIC DUMMY LOAD	TAKASAGO	FK-400L
7	CVCF	TAKASAGO	AA2000XG
8	DYNAMIC DIP SIMULATOR	CYBERNETICS	PSA-210
9	CONTROLLED TEMP. CHAMBER	ESPEC	SU-641
10	SPECTRUM ANALYZER EMI TEST RECEIVER	ROHDE & SCHWARZ	ESCI
11	RF SELECTOR	TOYO, CORP	NS4900
12	AMN	SCHWARZBECK	NNLK8121
13	ANTENNA (BICONICAL ANTENNA)	TESEQ	CBL6111D

## 2. 特性データ

## Characteristics

RDS60-24

## 2.1 静特性

## Steady state data

(1) 入力・負荷・温度変動／出力起動・低下電圧

Regulation - line and load, Temperature drift / Start up voltage and Drop out voltage

5V

## 1. Regulation - line and load

Condition

Ta : 25 °C

Iout \ Vin	18VDC	24VDC	32VDC	line regulation	
0%	5.072V	5.067V	5.066V	6mV	0.120%
50%	5.039V	5.035V	5.034V	5mV	0.100%
100%	5.004V	5.000V	4.999V	5mV	0.100%
load regulation		68mV	67mV		
		1.360%	1.340%	1.340%	

## 2. Temperature drift

Conditions

Vin : 24 VDC

Iout : 100 %

Ta	-20°C	+25°C	+50°C	temperature stability	
Vout	5.022V	5.000V	5.015V	22mV	0.440%

## 3. Start up voltage and Drop out voltage

Conditions

Ta : 25 °C

Iout : 100 %

Start up voltage (Vin)	16.3VDC
Drop out voltage (Vin)	16.4VDC

12V

## 1. Regulation - line and load

Condition

Ta : 25 °C

Iout \ Vin	18VDC	24VDC	32VDC	line regulation	
0%	12.047V	12.046V	12.046V	1mV	0.008%
50%	12.035V	12.032V	12.031V	4mV	0.033%
100%	12.019V	12.015V	12.013V	6mV	0.050%
load regulation		28mV	31mV		
		0.233%	0.258%	0.275%	

24V

## 1. Regulation - line and load

Condition

Ta : 25 °C

Iout \ Vin	18VDC	24VDC	32VDC	line regulation	
0%	24.096V	24.190V	24.236V	140mV	0.583%
50%	24.086V	24.085V	24.111V	26mV	0.108%
100%	24.076V	24.074V	24.084V	10mV	0.042%
load regulation		20mV	116mV		
		0.083%	0.483%	0.633%	

## 2. Temperature drift

Conditions

Vin : 24 VDC

Iout : 100 %

Ta	-20°C	+25°C	+50°C	temperature stability	
Vout	24.074V	23.999V	23.966V	108mV	0.450%

## 3. Start up voltage and Drop out voltage

Conditions

Ta : 25 °C

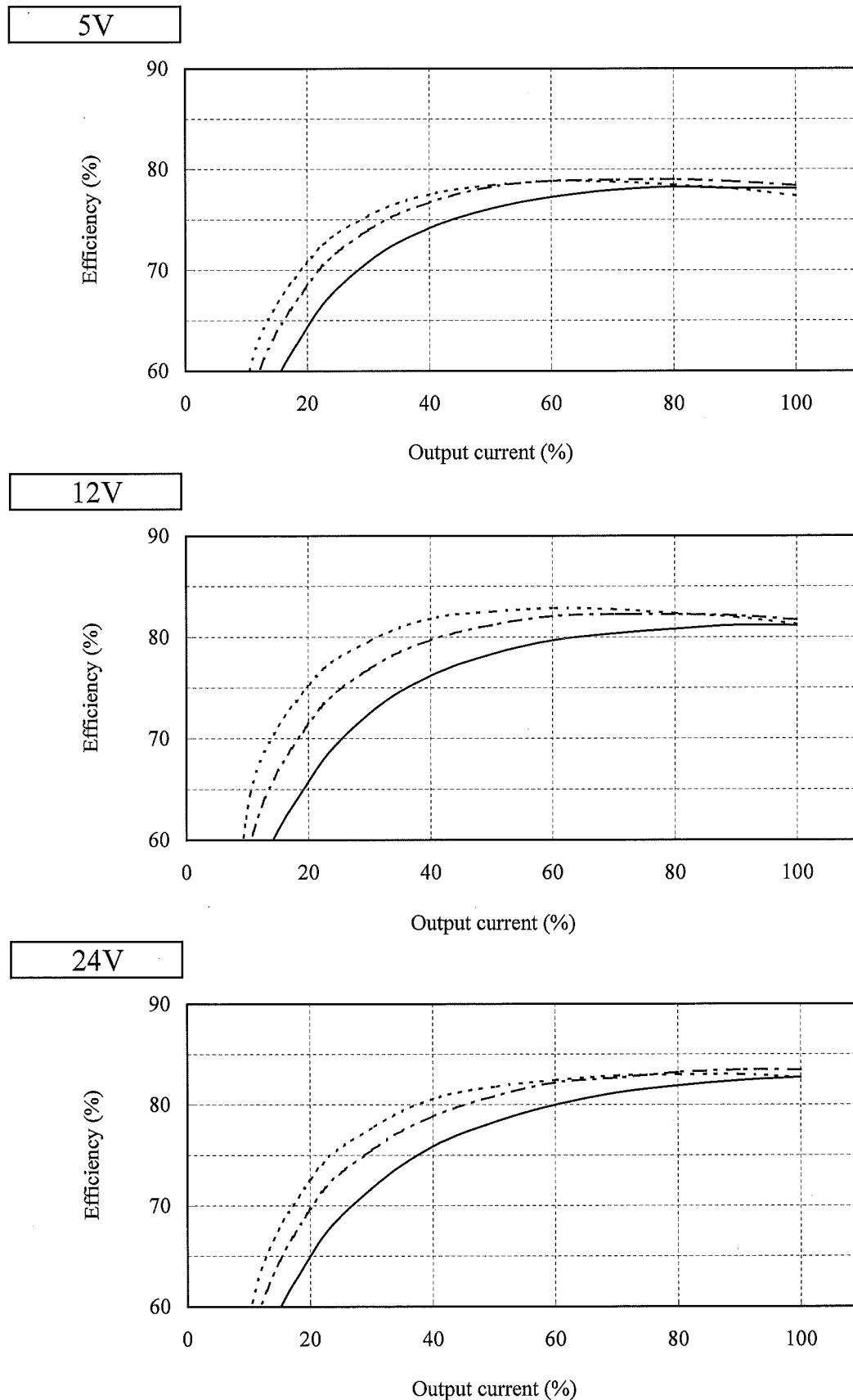
Iout : 100 %

Start up voltage (Vin)	15.8VDC
Drop out voltage (Vin)	14.0VDC

## (2) 効率対出力電流

Efficiency vs. Output current

Conditions    Vin : 18 VDC    -----  
                   24 VDC    - - - - -  
                   32 VDC    —————  
                   Ta : 25 °C

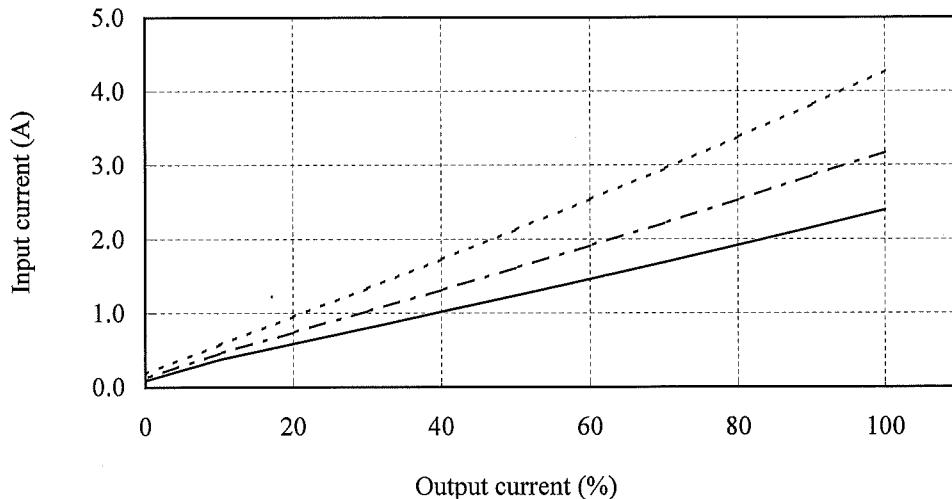


## (3) 入力電流対出力電流

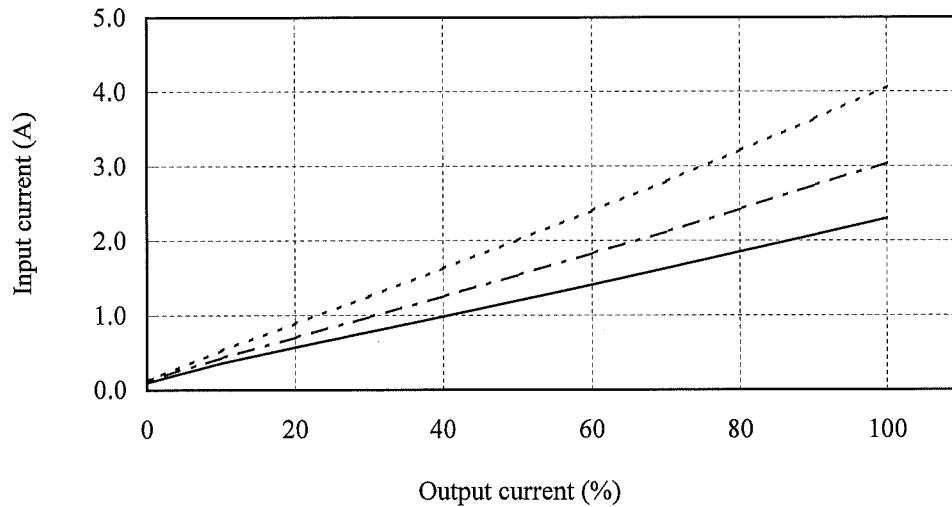
Input current vs. Output current

Conditions    Vin : 18 VDC -----  
                  24 VDC - - - - -  
                  32 VDC —————  
Ta : 25 °C

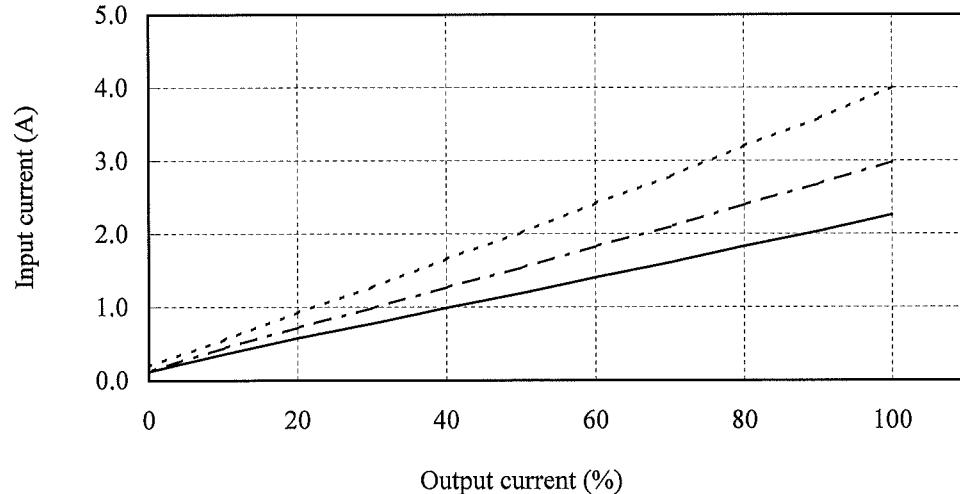
5V



12V



24V



## (4) 入力電力対出力電流

Input power vs. Output current

5V

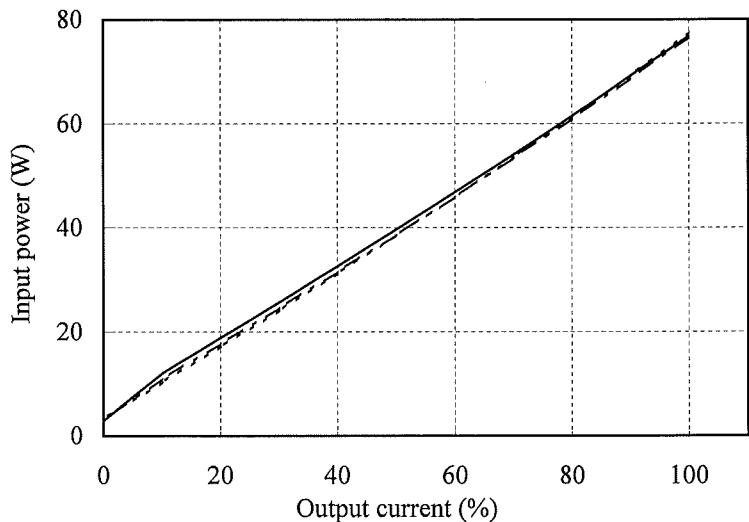
Conditions Iout : 0%

Vin	Input power
18VDC	3.3W
24VDC	2.9W
32VDC	3.0W

Conditions CNT (RC) : OFF

Vin	Input power
18VDC	0.2W
24VDC	0.4W
32VDC	0.8W

Conditions Vin : 18 VDC -----  
 24 VDC - - -  
 32 VDC —————  
 Ta : 25 °C



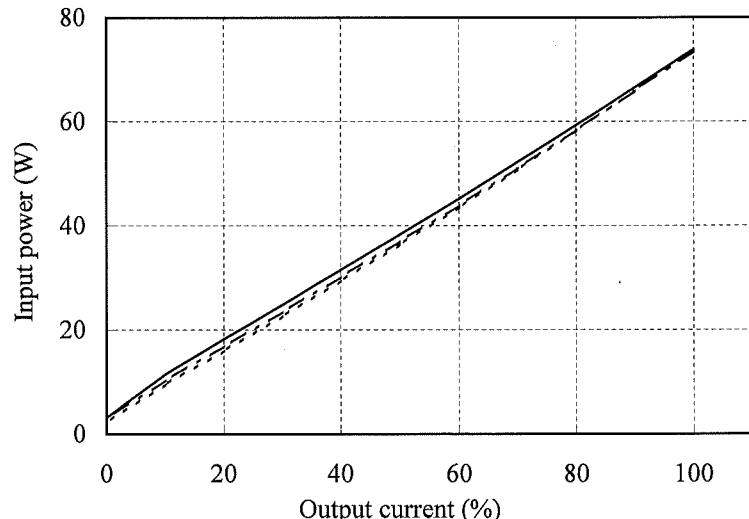
12V

Conditions Iout : 0%

Vin	Input power
18VDC	2.3W
24VDC	3.0W
32VDC	3.2W

Conditions CNT (RC) : OFF

Vin	Input power
18VDC	0.2W
24VDC	0.4W
32VDC	0.9W



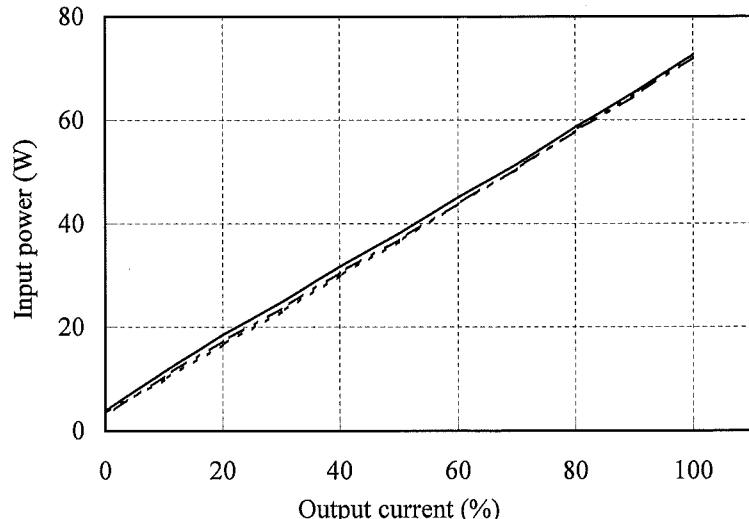
24V

Conditions Iout : 0%

Vin	Input power
18VDC	3.5W
24VDC	3.1W
32VDC	4.0W

Conditions CNT (RC) : OFF

Vin	Input power
18VDC	0.2W
24VDC	0.4W
32VDC	0.8W

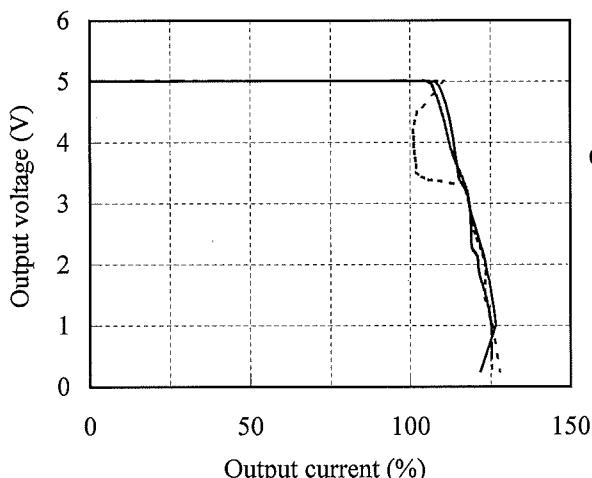


**2.2 過電流保護特性**

Over current protection (OCP) characteristics

Conditions    Vin :    18 VDC    -----  
                   24 VDC    -----  
                   32 VDC    -----  
                   Ta :    25 °C

**5V**



**2.3 過電壓保護特性**

Over voltage protection (OVP) characteristics

Conditions    Vin :    24 VDC  
                   Iout :    0 %  
                   Ta :    25 °C

OVP Point →

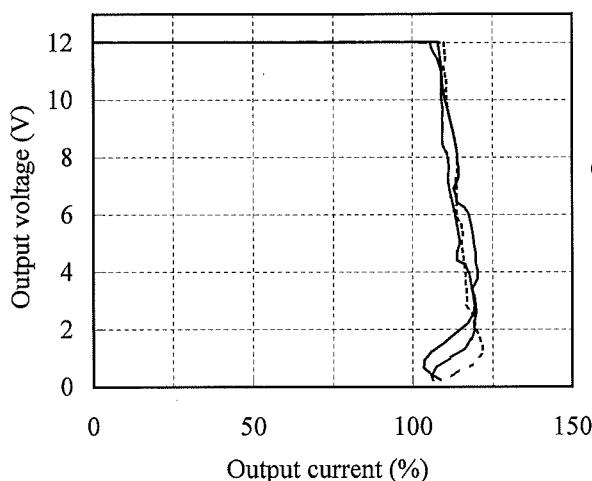
Vout →

0V →

2V/DIV

500ms/DIV

**12V**



OVP Point →

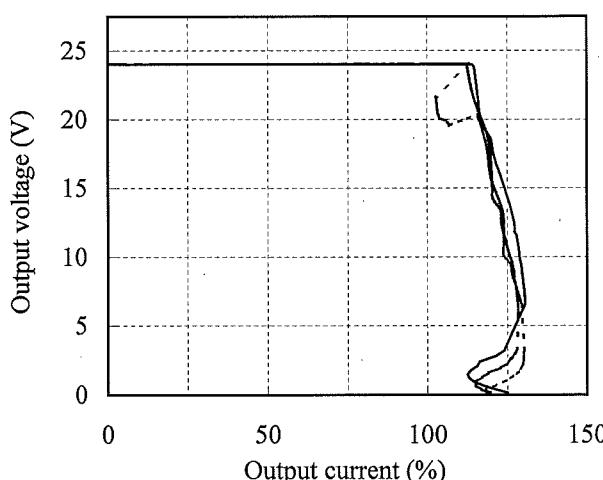
Vout →

0V →

5V/DIV

500ms/DIV

**24V**



OVP Point →

Vout →

0V →

10V/DIV

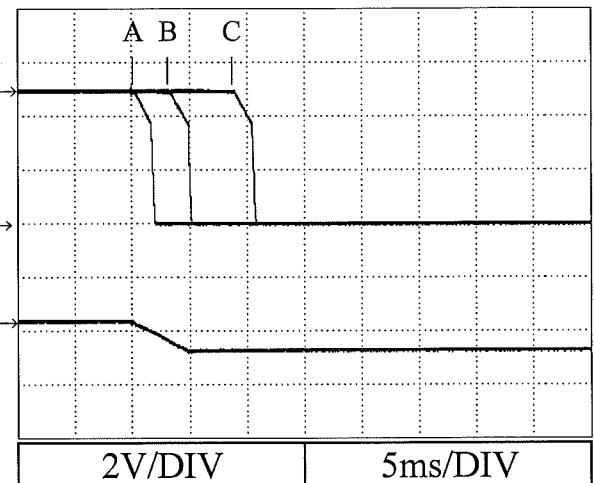
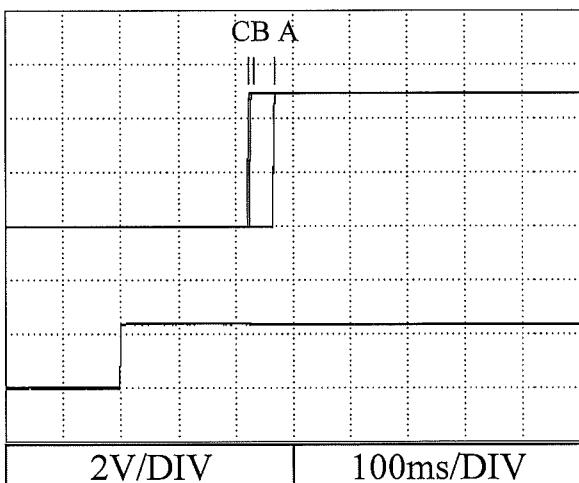
500ms/DIV

2.4 出力立ち上がり・立ち下がり特性

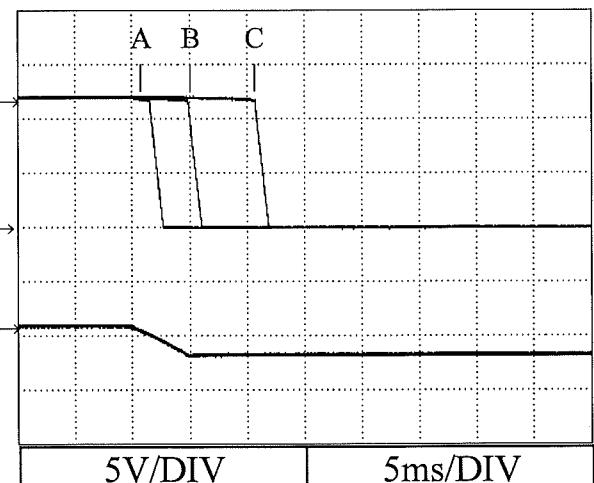
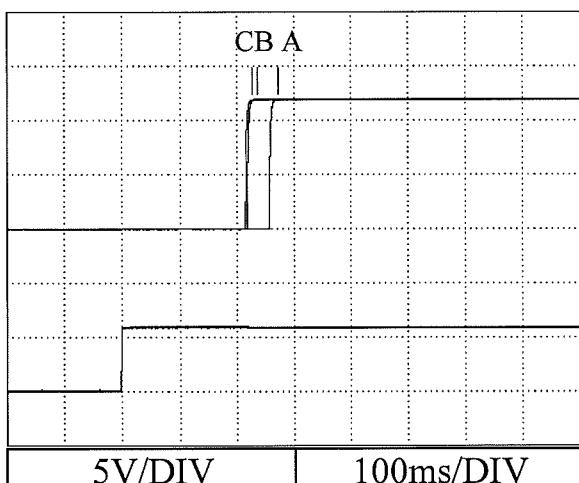
Output rise/fall characteristics

Conditions  
 Vin : 18 VDC (A)  
 24 VDC (B)  
 32 VDC (C)  
 Iout : 100 %  
 Ta : 25 °C

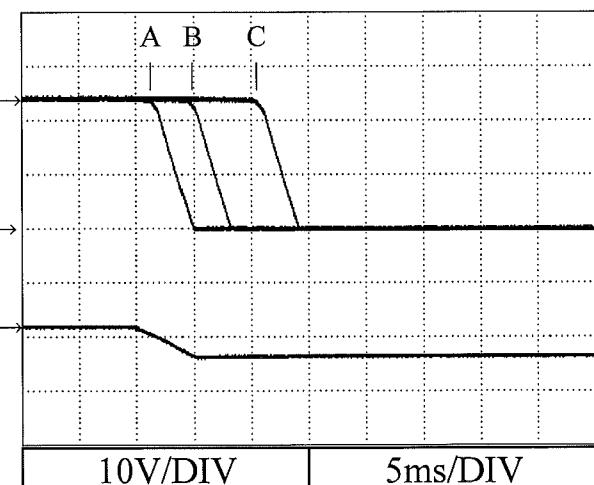
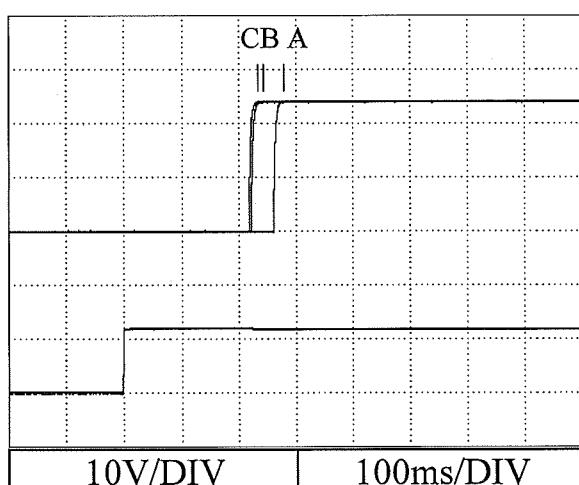
5V

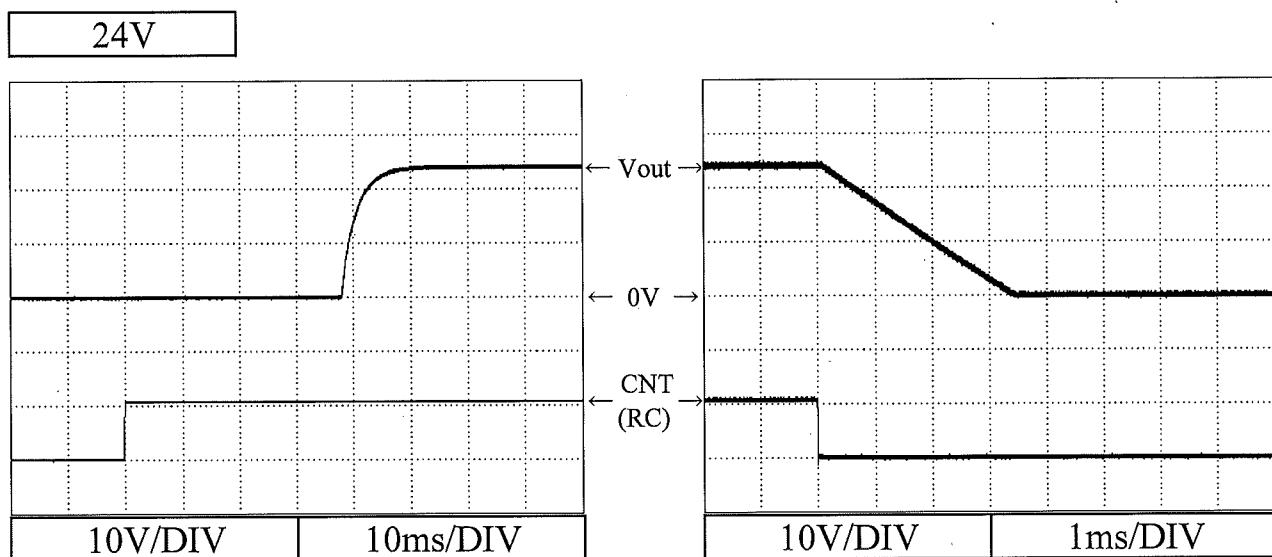
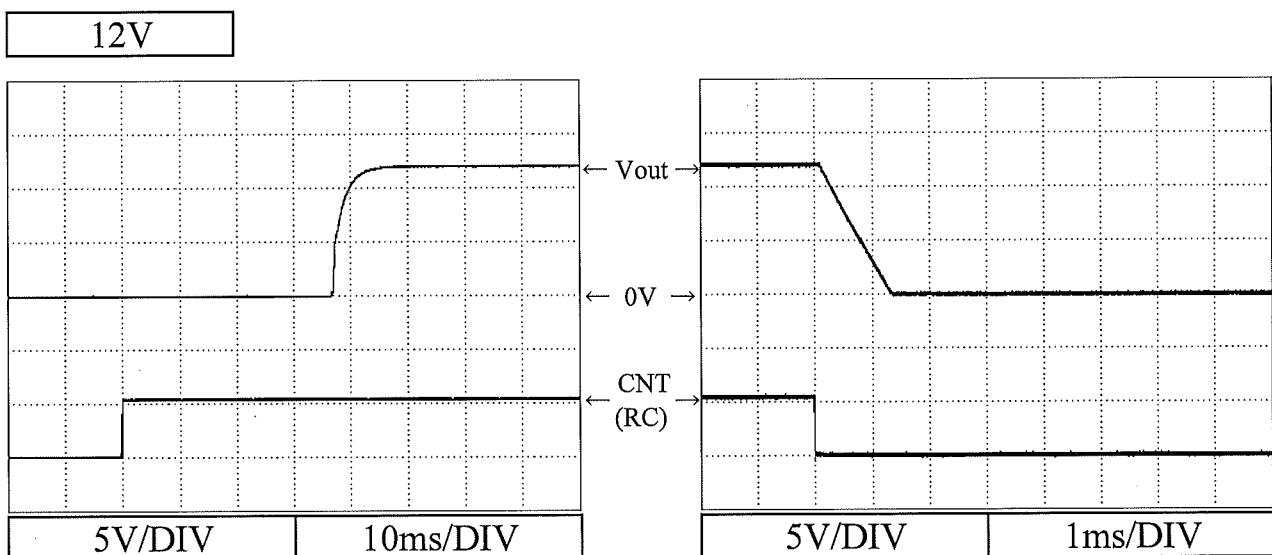
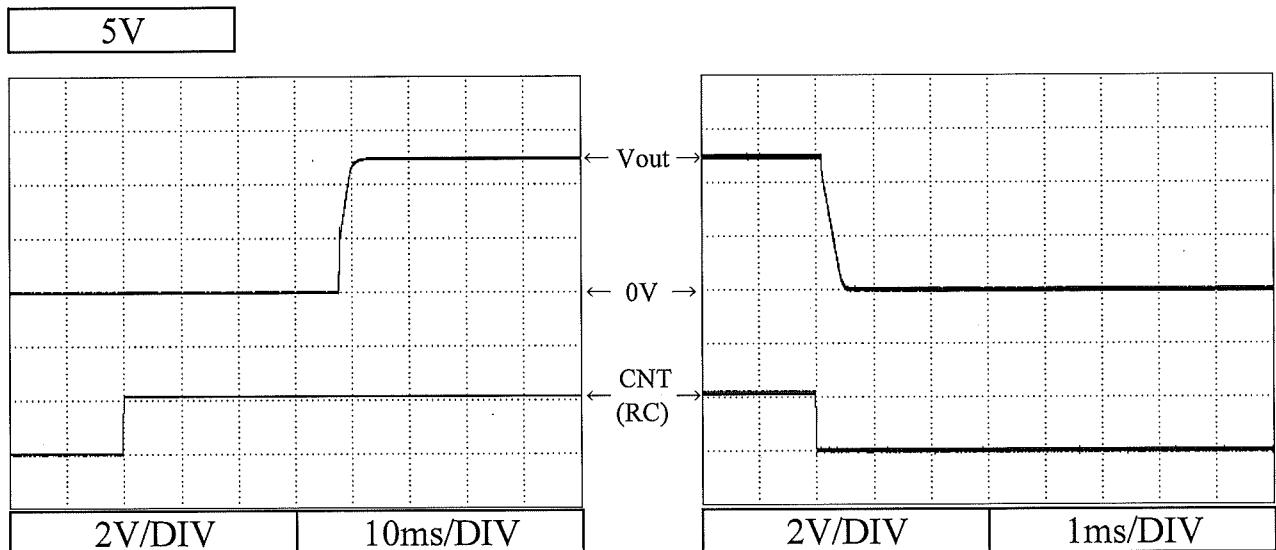


12V



24V



2.5 ON/OFFコントロール時出力立ち上がり・立ち下がり特性  
Output rise/fall characteristics with ON/OFF controlConditions      Vin : 24 VDC  
                  Iout : 100 %  
                  Ta : 25 °C

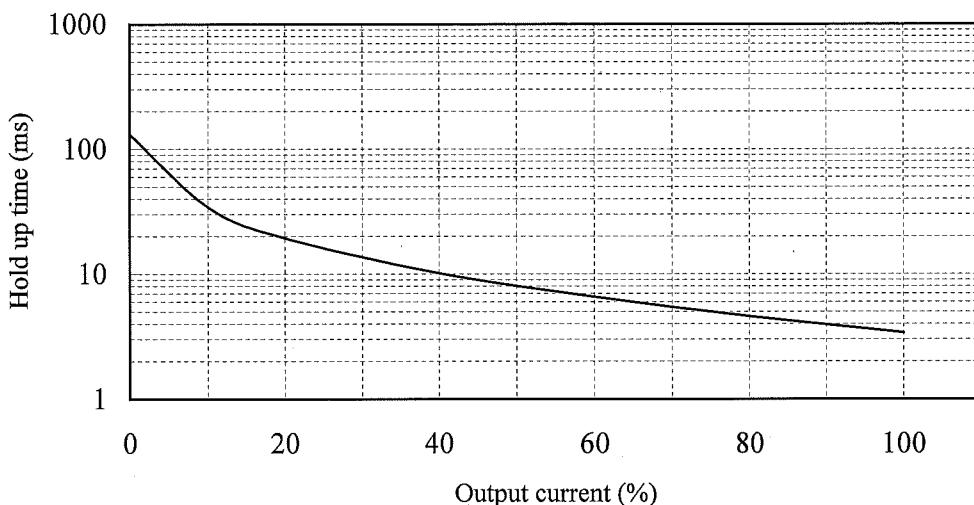
## 2.6 出力保持時間特性

Hold up time characteristics

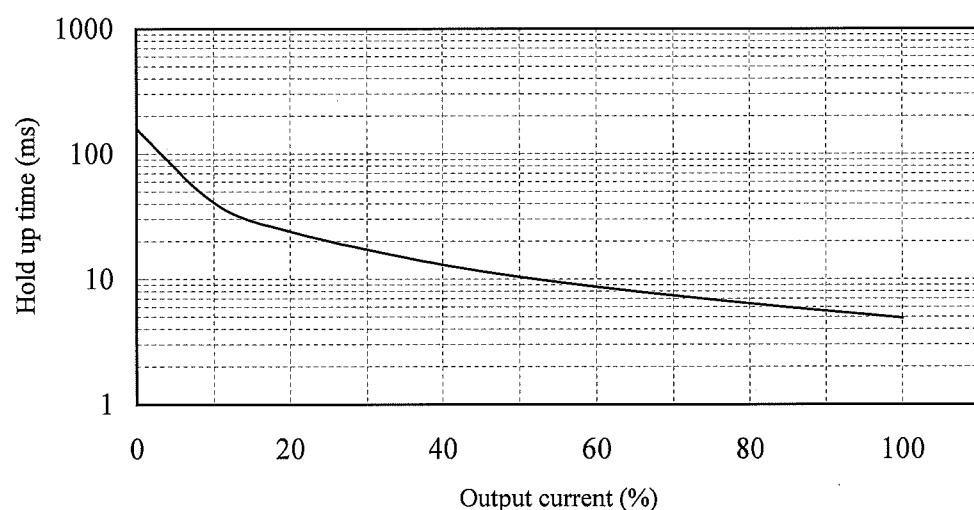
Conditions Vin : 24 VDC

Ta : 25 °C

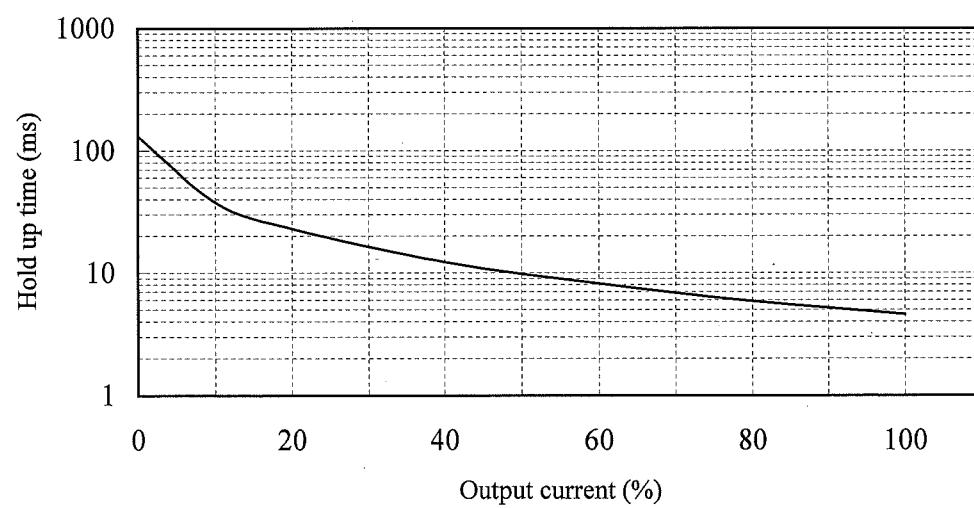
5V



12V

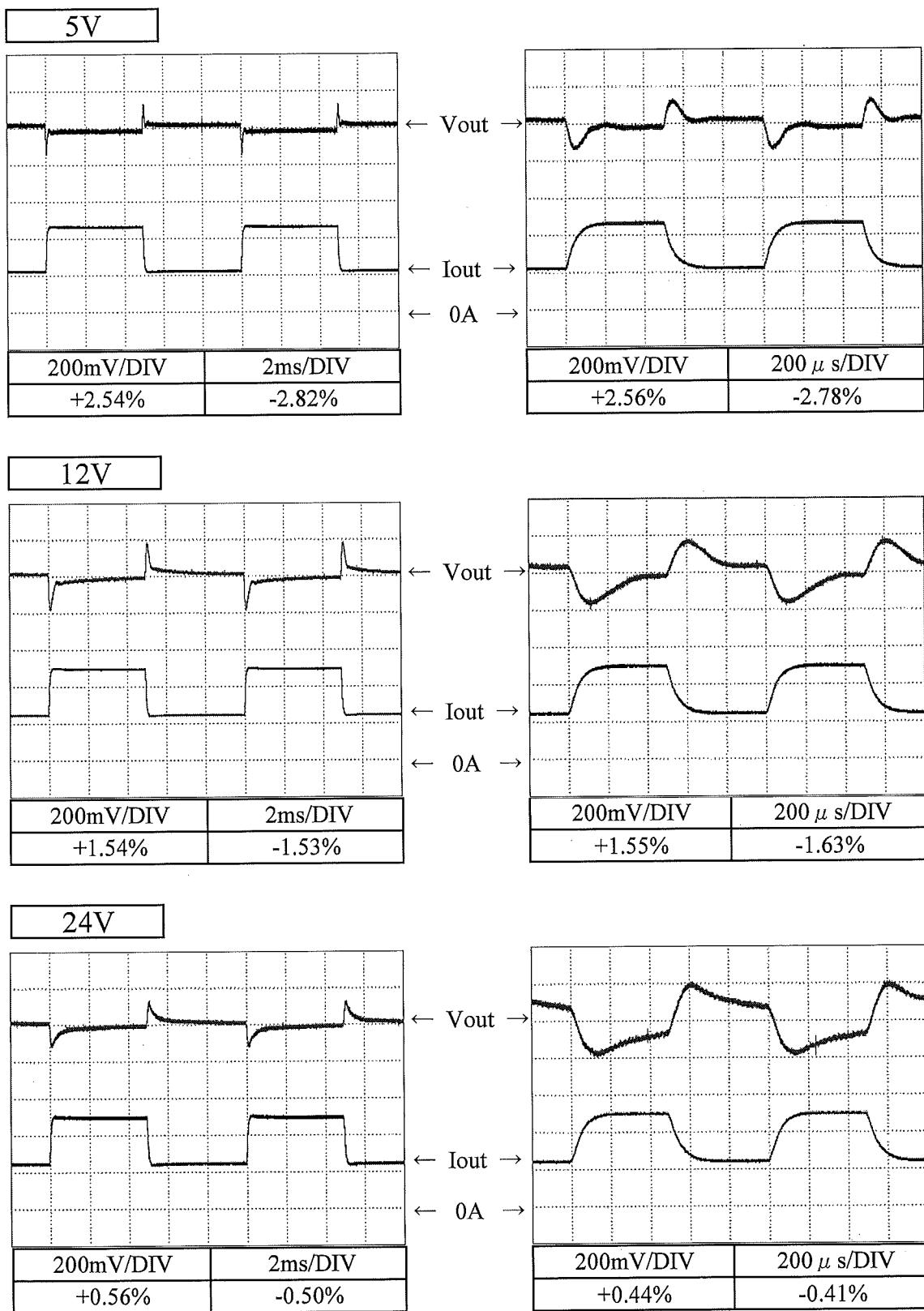


24V



2.7 過渡応答（負荷急変）特性  
Dynamic load response characteristics

Conditions      Vin : 24 VDC  
                  Io : 50 %  $\leftrightarrow$  100 %  
                  (tr = tf = 100us)  
                  Ta : 25 °C

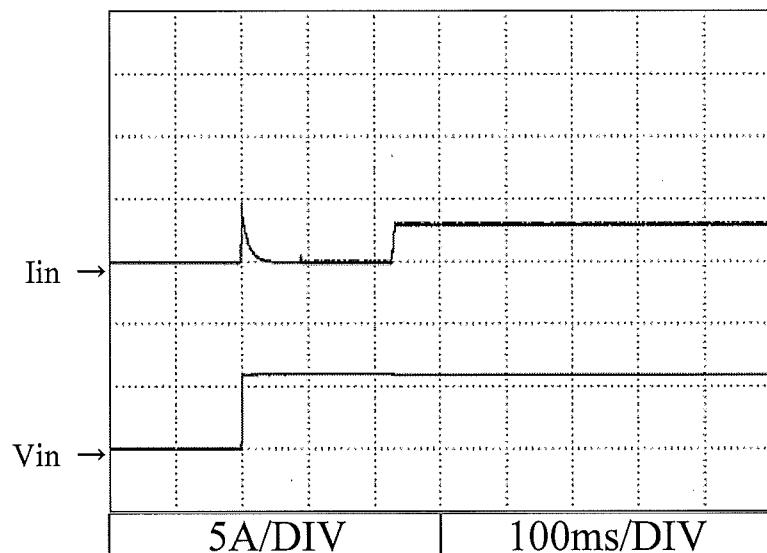
f = 100Hzf = 1kHz

## 2.8 入力サージ電流（突入電流）特性

Inrush current waveform

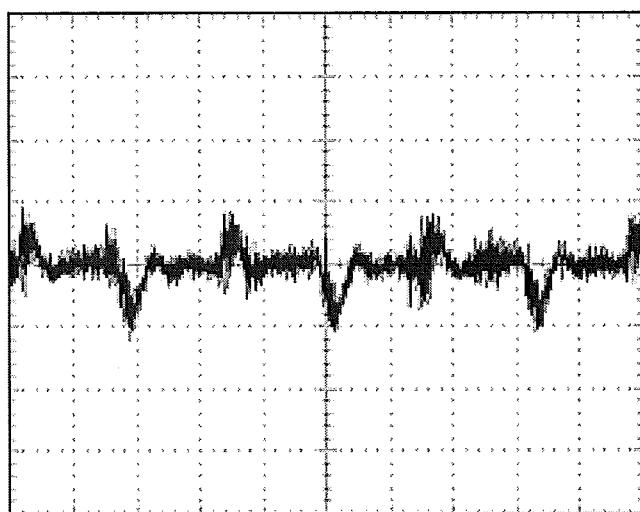
Conditions      Vin : 24 VDC  
                  Iout : 100 %  
                  Ta : 25 °C

5V



2.9 出力リップル、ノイズ波形  
Output ripple and noise waveformConditions  
Vin : 24 VDC  
Iout : 100 %  
Ta : 25 °CNORMAL MODE

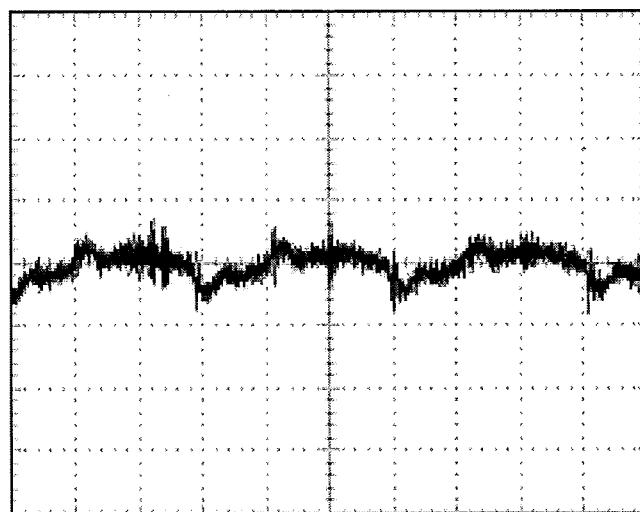
5V



10mV/DIV

1μs/DIV

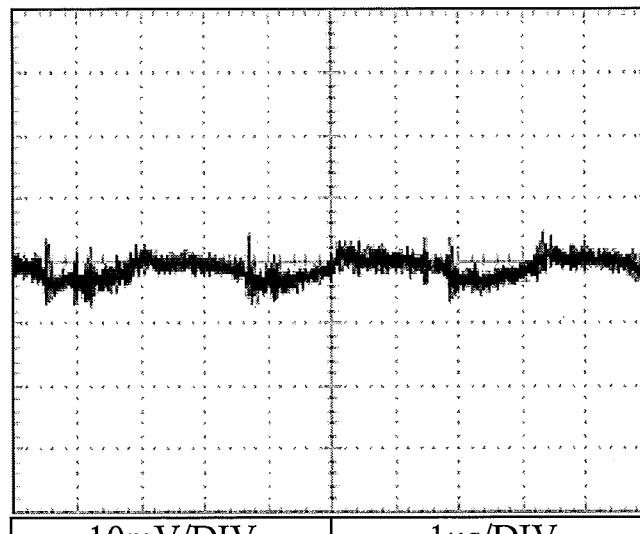
12V



10mV/DIV

1μs/DIV

24V



10mV/DIV

1μs/DIV

## 2.10 E M I 特性

## Electro-Magnetic Interference characteristics

雜音端子電圧

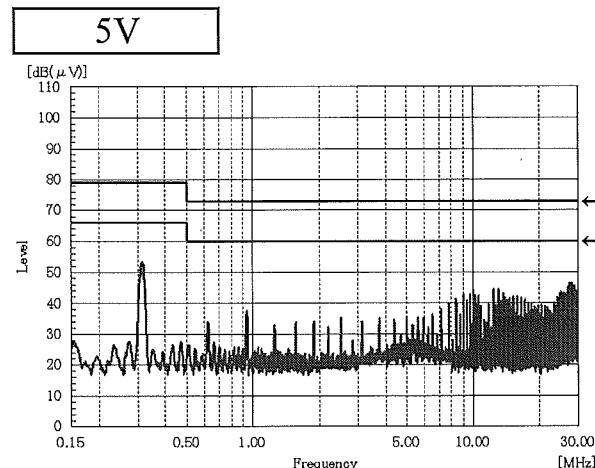
Conducted Emission

Conditions

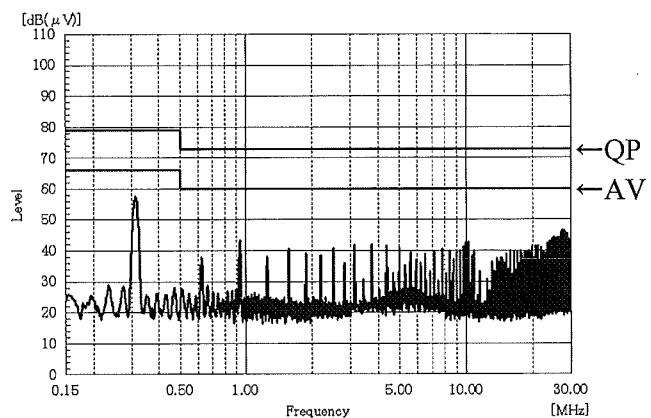
Vin : 24 VDC

Iout : 100 %

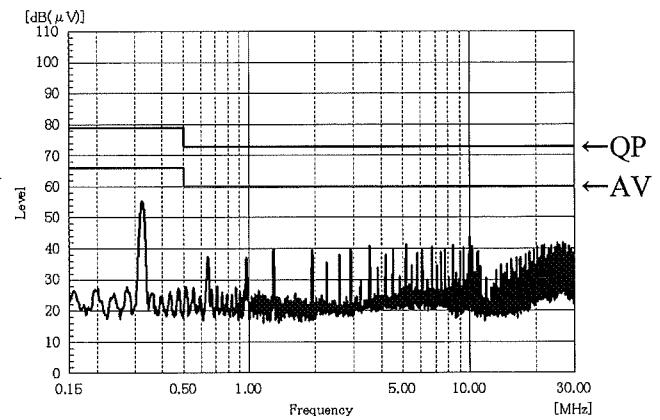
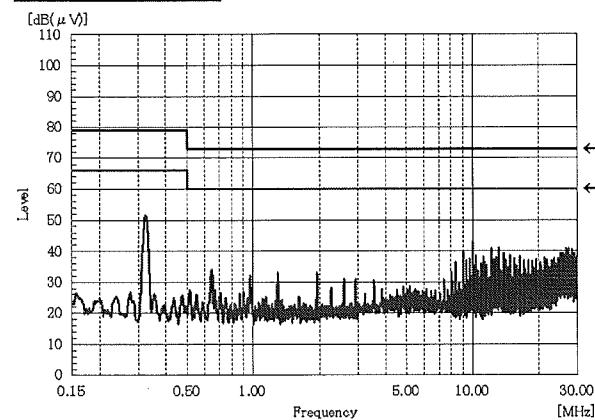
Phase : N (-Vin side)



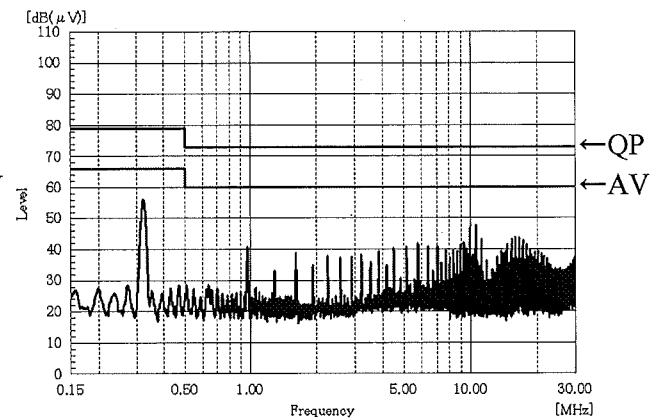
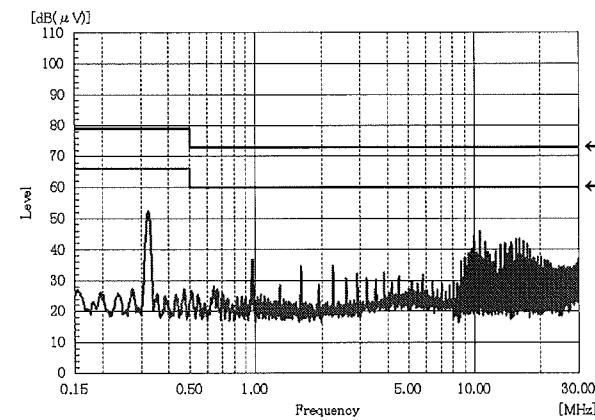
Phase : L (+Vin side)



12V



24V



EN55011-A,EN55022-Aの限界値はVCCI class Aの限界値と同じです。

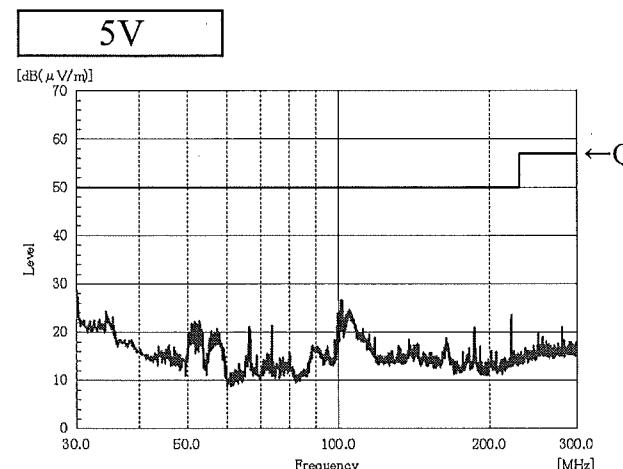
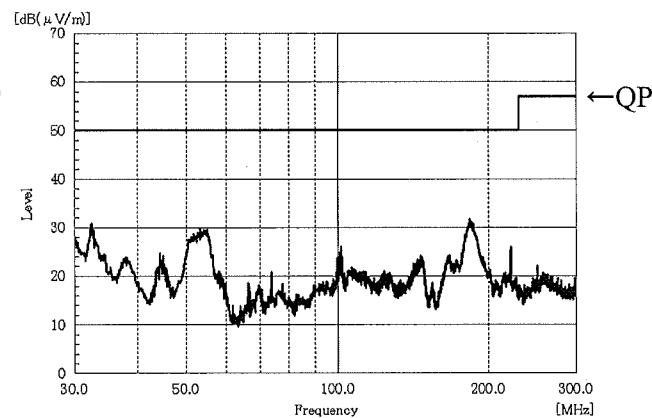
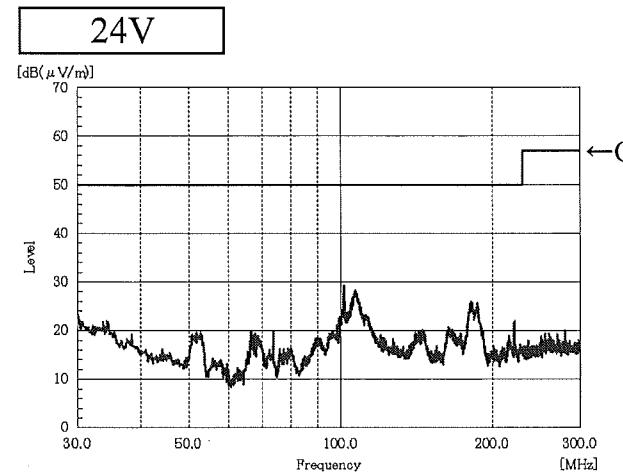
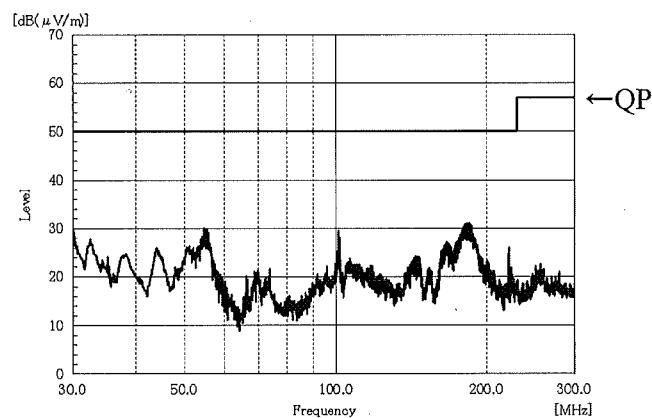
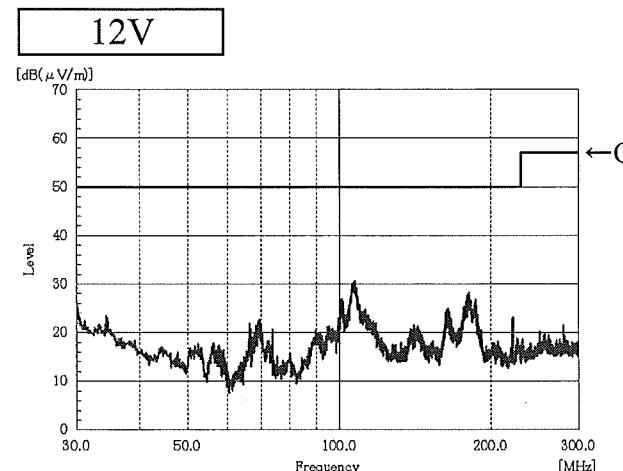
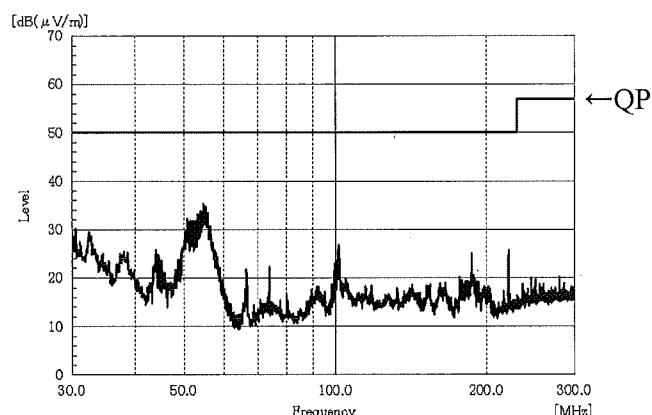
Limit of EN55011-A,EN55022-A are same as its VCCI class A.

表示はピーク値です。  
Indication is peak values.

雜音電界強度  
Radiated Emission

Conditions

Vin : 24 VDC  
Iout : 100 %

HORIZONTALVERTICAL

EN55011-A, EN55022-Aの限界値はVCCI class Aの限界値と同じです。  
Limit of EN55011-A, EN55022-A are same as its VCCI class A.

表示はピーク値です。  
Indication is peak values.